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FSA660—2:1 MIPI C-PHY (5.7 Gbps) 1-Data Lane Switch

Features

- Switch Type: SPDT(3x)
- Signal Types:
 MIPI, C-PHY
- V_{CC}: 1.5 to 5.0 V
- Input Signals: 0 to 2.1 V
- R_{ON}: 5.4 Ω Typical
- ΔR_{ON}: 0.1 Ω Typical
- R_{ON_FLAT}: 0.9 Ω Typical
- Iccz:1 µA Maximum
- Icc: 12 µA Typical
- OIRR: -28 dB Typical
- Bandwidth: 5G Hz Typical
- I_L: -1.0 dB Typical
- Xtalk: -44 dB Typical
- Con: 0.8 pF Typical

Description

The FSA660 is a one-data-lane MIPI, C-PHY switch. This Single-Pole, Double-Throw (SPDT) switch is optimized for switching between two high-speed or lowpower MIPI sources. The FSA660 is designed for the MIPI specification and allows connection to a CSI or DSI module.

Applications

- Smart phones
- Tablets
- Laptops
- Displays

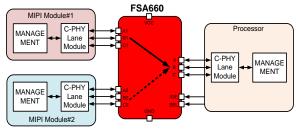
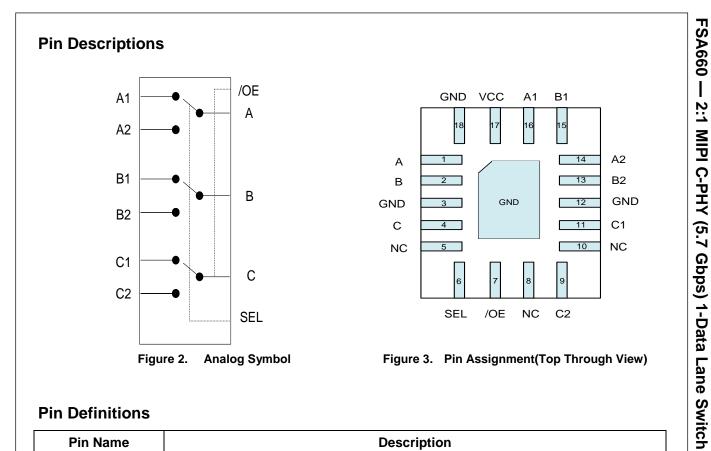


Figure 1. Typical Application

Ordering Information

Part Number	Operating Temperature Range	Package		
FSA660TMX	-40 to +85°C	18-Lead, Quad, Ultra-ultrathin Molded Leadless Package (TMLP), 2.0 mm x 2.8 mm x 0.375 mm	LS	



Pin Definitions

Pin Name	Description					
A1	1-Side Data Path A					
B1		1-Side Data Path B				
C1		1-Side	Data Path C			
A2		2-Side	Data Path A			
B2		2-Side	Data Path B			
C2		2-Side Data Path C				
А		Common Data Path A				
В		Common Data Path B				
С		Common Data Path C				
/OE		Outp	ut Enable			
SEL	Control Pin	SEL=0	A=A1,B=B1,C=C1			
JEL	Control Fill	SEL=1	A=A2,B=B2,C=C2			
VCC	Power					
GND	Ground					
NC	No Connect					

Truth Table

SEL	/OE	Function
HIGH	LOW	A=A2,B=B2,C=C2
LOW	LOW	A=A1,B=B1,C=C1
Х	HIGH	A,B,C Data Ports High Impedance

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit	
Vcc	Supply Voltage		-0.5	6.0	V	
V _{CNTRL}	DC Input Voltage (SEL, /OE) ⁽¹⁾		-0.5	V _{cc}	V	
Vsw	DC Switch I/O Voltage ^(1,2)		-0.3	2.1	V	
I _{IK}	DC Input Diode Current		-50		mA	
I _{sw}	DC Switch Current			25	mA	
T _{STG}	Storage Temperature		-65	+150	°C	
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)			1		
	Human Body Model, JEDEC: JESD22-A114	All Pins	2			
ESD	IEC 61000 2.4 Lovel 4 for Switch Disc	Contact	8		kV	
E3D	IEC 61000-2-4, Level 4, for Switch Pins		15		κV	
	Charged Device Model, JESD22-C101		1			

Notes:

- 1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.
- 2. V_{SW} refers to analog data switch paths.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Min.	Max.	Unit
V _{CC}	Supply Voltage		1.5	5.0	V
V _{CNTRL}	Control Input Voltage (SEL, /OE) ⁽³⁾		0	5.0	V
N/	Switch I/O Voltage HS Mode LP Mode		0	0.54	V
Vsw			0	1.3	v
T _A	Operating Temperature		-40	+85	°C

Note:

3. The control inputs must be held HIGH or LOW; they must not float.

DC and Transient Characteristics

All typical values are at $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A = -40°C to +85°C			
				Min.	Тур.	Max.	Unit
VIK	Clamp Diode Voltage SEL, /OE	I _{IN} =-18 mA	1.5	-1.2		-0.6	V
Ік	Clamp Diode Current (Switch Pins)	VIN=-0.3 V	0			18	μΑ
		SEL, /OE	1.5	1.3			V
VIH	Control Input Voltage High	SEL, /OE	3.6	1.4			V
		SEL, /OE	5.0	1.5			V
		SEL, /OE	1.5			0.4	V
VIL	Control Input Voltage Low	SEL, /OE	3.6			0.4	V
		SEL, /OE	5.0			0.4	V
I _{IN}	Control Input Leakage	V_{SW} = 0 to 2.0 V V_{CNTRL} =0 to V_{CC}	5.0	-500		500	nA
I _{OZ}	Off-State Leakage for Open Data Paths	$V_{SW}\text{=}~0.0 \leq \text{DATA} \leq 2.0~\text{V}$	5.0	-500		500	nA
I _{CL}	On-State Leakage for Closed Data Paths ⁽⁴⁾	$V_{SW}\text{=}~0.0 \leq \text{DATA} \leq 2.0~\text{V}$	5.0	-500		500	nA
I _{OFF}	Power-Off Leakage Current (All I/O Ports)	V _{SW} = 0.0 V to 2.0 V	0	-500		500	nA
R _{ON}	Switch On Resistance	V _{SW} = 0 V, I _{ON} =-8 mA	1.5		5.4	8.0	Ω
ΔR_{ON}	Difference in R _{ON} Between Positive-Negative	V_{SW} = 0 V, I _{ON} =-8 mA,	1.5		0.1		Ω
$R_{\text{ONF}_{\text{FLAT}}}$	Flatness for R _{ON}	$\label{eq:V_SW} \begin{array}{l} V_{SW} \!\!\!\!= 0 \leq \! DATA \leq \! 2.0 \ V, \\ I_{ON} \!\!\!\!= \!$	1.5		0.9		Ω
Icc	Quiescent Supply Current	$V_{OE}=0, V_{SEL}=0 \text{ or } V_{CC}, I_{OUT}=0$	5.0		12	30	μΑ
I _{CCZ}	Quiescent Supply Current (High Impedance)	$V_{SEL}=X, V_{/OE}=V_{CC}, I_{OUT}=0$	5.0			1	μA
I _{CCT}	Increase in Quiescent Supply Current	V _{SEL} =X, V _{/OE} =1.5 V	5.0		5	15	μΑ

Note:

4. For this test, the data switch is closed with the respective switch pin floating.

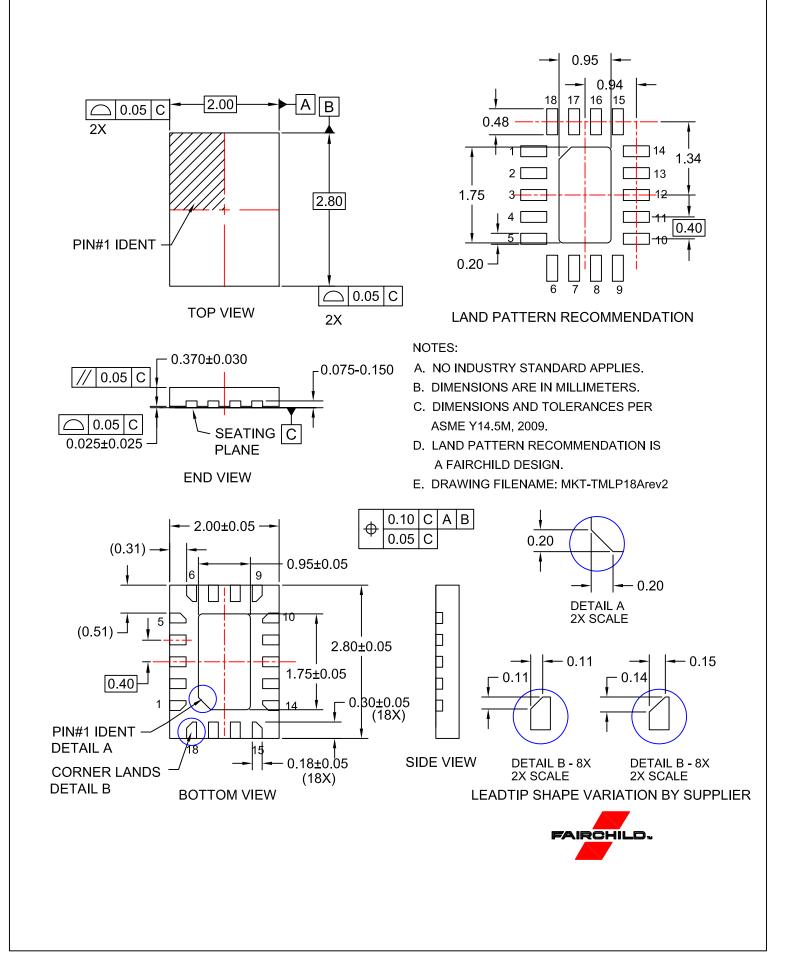
AC Electrical Characteristics

All typical value are for V_{CC} =3.6 V and $T_A {=} 25^\circ C$ unless otherwise specified.

Symbol	Parameter	Condition	V _{cc} (V)	T _A = -40°C to +85°C			Unit
				Min.	Тур.	Max.	Unit
t _{ON}	Turn-On Time, SEL to Output		1.5 to 5.0 V		350	600	ns
t _{OFF}	Turn-Off Time, SEL to Output		1.5 to 5.0 V		125	300	ns
t _{PD}	Propagation Delay ⁽⁵⁾	$C_L=$, $C_L=0$ pF, $R_L=50$ Ω ,	1.5 to 5.0 V		0.25		ns
t _{BBM}	Break-Before-Make ⁽⁵⁾		1.5 to 5.0 V	100		350	ns
t _{PEN}	Enable Time, /OE to Output	R _L =50 Ω, C _L =0 pF, V _{SW} =0.6 V	1.5 to 5.0 V		60	150	μs
t PDISEN	Disable Time, /OE to Output	R _L =50 Ω, C _L =0 pF, V _{SW} =0.6 V	1.5 to 5.0 V		35	240	ns
O _{IRR}	Off Isolation ⁽⁵⁾	V _S =0 dBm, R=50 Ω, f=2.5 GHz	3.6 V		-28		dB
Xtalk	Channel Crosstalk ⁽⁵⁾	V _S =0 dBm, R=50 Ω, f=2.5 GHz	3.6 V		-44		dB
IL	Insertion Loss ⁽⁵⁾	V_S =0 dBm, f=2.5 GHz, R _L =50 Ω , C _L =0 pF	3.6V		-1.0		dB
BW	-3 db Bandwidth ⁽⁵⁾	$V_{IN}=1 V_{pk-pk}, R_L=50 \Omega, C_L=0 pF (All Data Paths)$	3.6 V		5		GHz
t _{SK(P)}	Skew of Transitions of the Output ⁽⁵⁾	$\ensuremath{R_{PU}}\xspace=50\ \Omega$ to $V_{CC},\ensuremath{\text{f}}\xspace=2.5\ \text{GHz},\ensuremath{CL}\xspace=0\ \text{pF}$	3.6 V		6		ps
C _{IN}	Control Pin Input Capacitance ⁽⁵⁾	V _{CC} =0 V, f=1 MHz			2.7		pF
CON	On Capacitance ⁽⁵⁾	V _{CC} =3.3 V, f=2.5 GHz			0.8		pF
C_{OFF}	Off Capacitance ⁽⁵⁾	V _{CC} =3.3 V, f=2.5 GHz			0.6		pF

Note:

5. Guaranteed by characterization and design. Not production tested.



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